Electronic Supporting Information (ESI)

A facile growth process of highly single crystalline Ir_{1-x}V_xO₂ mixed metal oxide nanorods and their electrochemical properties

Sung Hee Chun^{*a,d*}, Hyun Yeong Kim^{*a,d*}, Hyesu Jang^{*a*}, Yejung Lee^{*a*}, Ara Jo^{*a*}, Nam-Suk Lee^{*b*}, Hak Ki Yu^{*c*}, Youngmi Lee^{*a*}, Myung Hwa Kim^{*a*}*, and Chongmok Lee^{*a*}*

^aDepartment of Chemistry & Nano Science, Ewha Womans University, Seoul, 03760, Korea ^bNational Institute for Nanomaterials Technology (NINT), Pohang University of Science and Technology (POSTECH), Pohang, 790-784, Korea ^cDeaprtment of Materials Science and Engineering and Department of Energy Systems Research, Ajou University, Suwon, 443-749, Korea ^dAuthors are equally contributed to this work.

*To whom all correspondence should be addressed: <u>myungkim@ewha.ac.kr</u>, <u>cmlee@ewha.ac.kr</u>

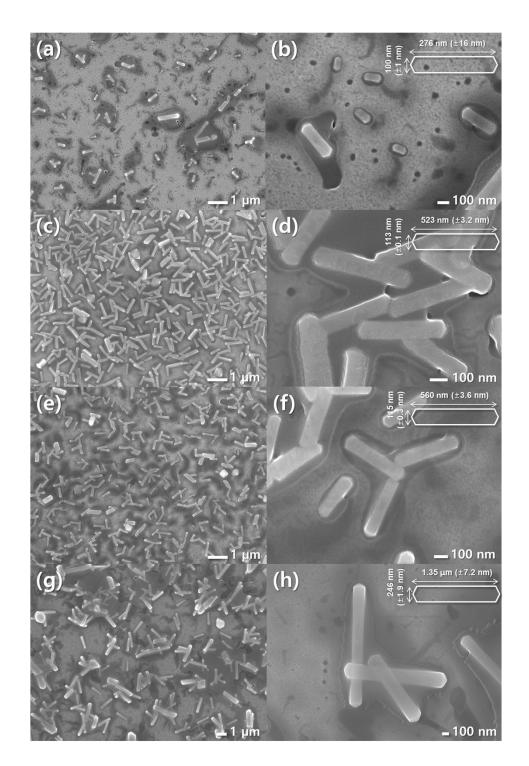


Fig. S1 SEM images for the time dependence of the growth process of $Ir_{0.34}V_{0.66}O_2$ mixed oxide nanorods. (a) and (b) for 10 min, (c) and (d) for 30 min, (e) and (f) for 1 hour, (g) and (h) for 1.5 hour, respectively.



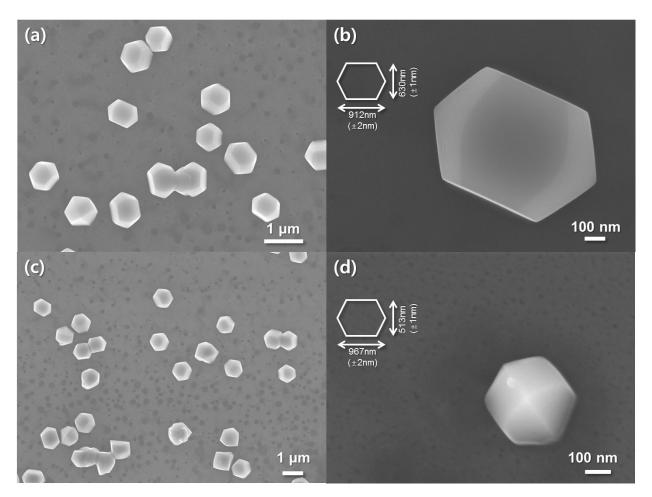


Fig. S2 SEM images for the time dependence of the growth process of $Ir_{0.87}V_{0.13}O_2$ mixed oxide nanorods. (a) and (b) for 1 h, (c) and (d) for 3hrs, respectively.

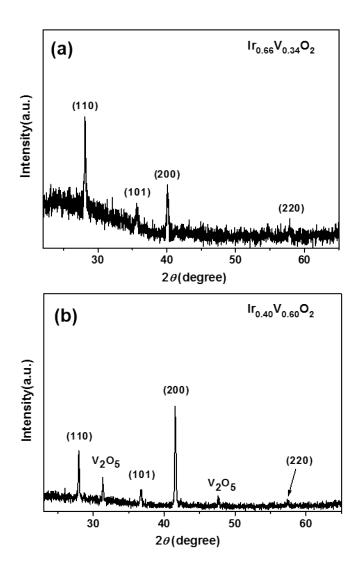


Fig. S3 X-ray diffraction patterns of $Ir_{1-x}V_xO_2$ mixed metal oxide nanorods on a Si substrate for (a) $Ir_{0.66}V_{0.34}O_2$ and (b) $Ir_{0.40}V_{60}O_2$, respectively.

Fig. S4

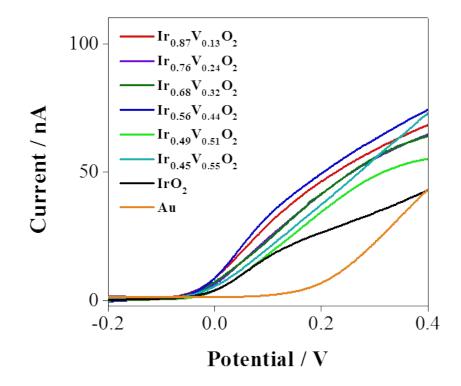


Fig. S4 LSV waves at $Ir_{1-x}V_xO_2$ nanorods on GC, iridium oxide (black) and Au microwire (orange) in 0.1 M N₂-purged PBS solution (pH 7.4) containing 0.5 mM AA with a scan rate of 10 mV s⁻¹.